Low Noise Transistor NPN Silicon



ON Semiconductor Preferred Device

MAXIMUM RATINGS

THERMAL CHARACTERISTICS

Characteristic

Thermal Resistance, Junction to Ambient

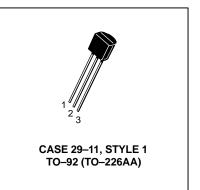
Thermal Resistance, Junction to Case

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V _{CEO}	45	Vdc
Collector–Base Voltage	V _{CBO}	45	Vdc
Emitter-Base Voltage	V _{EBO}	6.5	Vdc
Collector Current — Continuous	Ι _C	200	mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	625 5.0	mW mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	PD	1.5 12	Watts mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C

Symbol

 $R_{\theta JA}^{(1)}$

 $\mathsf{R}_{\theta \mathsf{JC}}$



COLLECTOR 3 BASE 1

EMITTER

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS						
Collector–Emitter Breakdown Voltage ⁽²⁾ ($I_C = 10 \text{ mAdc}, I_B = 0$)	V _{(BR)CEO}	45	_	_	Vdc	
Collector–Base Breakdown Voltage $(I_C = 100 \ \mu Adc, I_E = 0)$	V _{(BR)CBO}	45	_	_	Vdc	
Emitter–Base Breakdown Voltage $(I_E = 10 \ \mu Adc, I_C = 0)$	0		_	_	Vdc	
Collector Cutoff Current ($V_{CB} = 30 \text{ Vdc}, I_E = 0$)	I _{CBO}	—	1.0	50	nAdc	

Max

200

83.3

Unit

°C/W

°C/W

1. $R_{\theta JA}$ is measured with the device soldered into a typical printed circuit board.

2. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%.

Preferred devices are ON Semiconductor recommended choices for future use and best overall value.

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Characteristic	Symbol	Min	Тур	Max	Unit
ON CHARACTERISTICS ⁽²⁾				•	
$ \begin{array}{l} \text{DC Current Gain} \\ (I_{C} = 10 \; \mu \text{Adc}, \; V_{CE} = 5.0 \; \text{Vdc}) \\ (I_{C} = 100 \; \mu \text{Adc}, \; V_{CE} = 5.0 \; \text{Vdc}) \\ (I_{C} = 1.0 \; \text{mAdc}, \; V_{CE} = 5.0 \; \text{Vdc}) \\ (I_{C} = 10 \; \text{mAdc}, \; V_{CE} = 5.0 \; \text{Vdc}) \end{array} $	h _{FE}	400 500 500 500	580 850 1100 1150	 1500	_
Collector–Emitter Saturation Voltage ($I_C = 10 \text{ mAdc}, I_B = 0.5 \text{ mAdc}$) ($I_C = 50 \text{ mAdc}, I_B = 5.0 \text{ mAdc}$)	V _{CE(sat)}	_	 0.08	0.2 0.3	Vdc
Base–Emitter On Voltage (I _C = 1.0 mAdc, V _{CE} = 5.0 Vdc)	V _{BE(on)}	_	0.6	0.7	Vdc
SMALL-SIGNAL CHARACTERISTICS					
Current–Gain — Bandwidth Product ($I_C = 1.0 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}, f = 100 \text{ MHz}$)	f _T	100	160	—	MHz
Collector–Base Capacitance $(V_{CB} = 5.0 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz})$	C _{cb}	_	1.7	3.0	pF
Emitter–Base Capacitance $(V_{EB} = 0.5 \text{ Vdc}, I_C = 0, f = 1.0 \text{ MHz})$	C _{eb}	_	5.6	6.5	pF
Noise Figure (I _C = 100 μ Adc, V _{CE} = 5.0 Vdc, R _S = 10 kΩ, f = 1.0 kHz) (I _C = 100 μ Adc, V _{CE} = 5.0 Vdc, R _S = 1.0 kΩ, f = 100 Hz)	NF		0.5 4.0	1.5 —	dB
Equivalent Short Circuit Noise Voltage (I _C = 100 μ Adc, V _{CE} = 5.0 Vdc, R _S = 1.0 kΩ, f = 100 Hz)	V _T	—	6.5	—	nV/√Hz

2. Pulse Test: Pulse Width \leq 300 $\mu s,$ Duty Cycle \leq 2.0%.

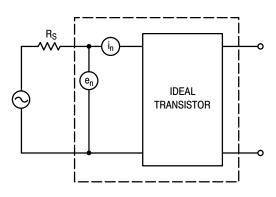
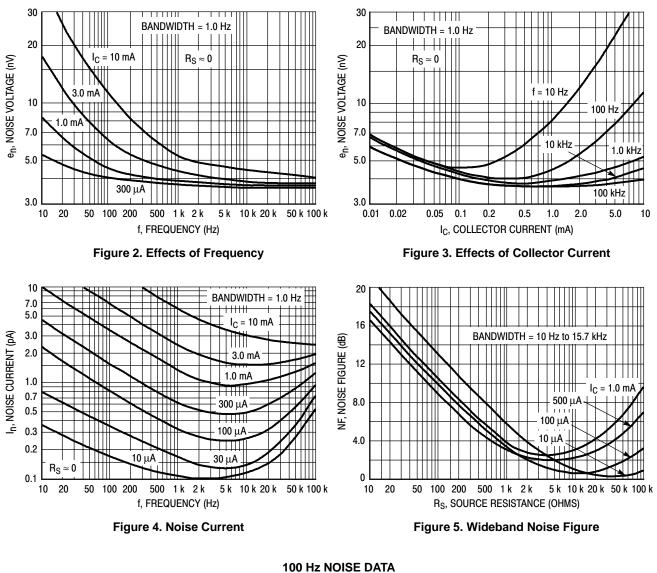


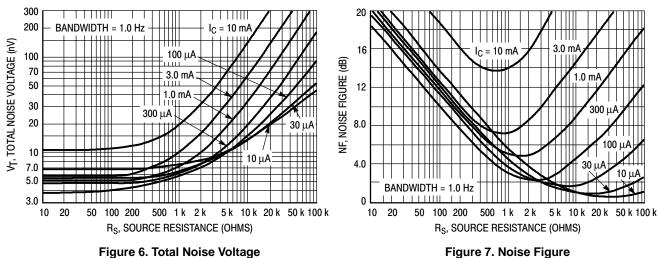
Figure 1. Transistor Noise Model

NOISE CHARACTERISTICS

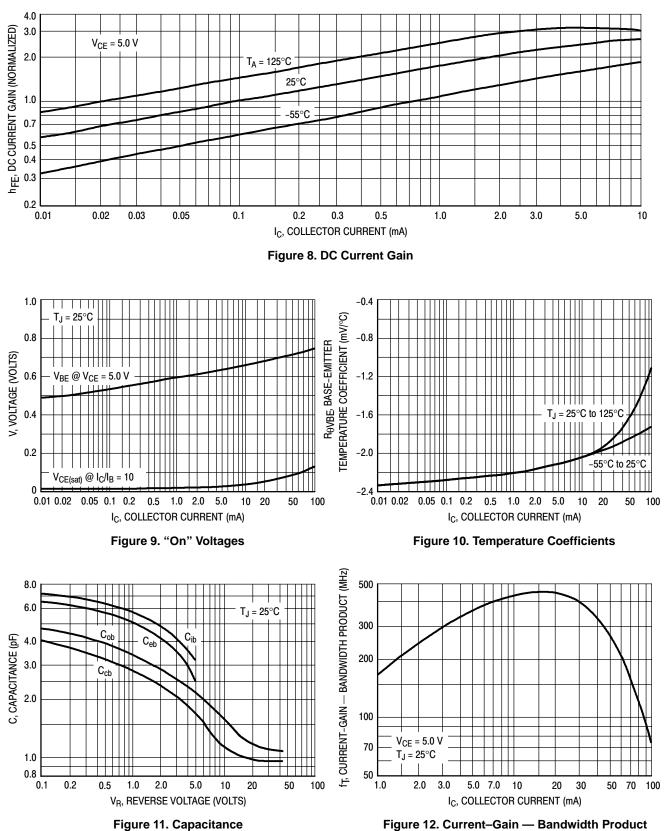
 $(V_{CE} = 5.0 \text{ Vdc}, T_A = 25^{\circ}C)$

NOISE VOLTAGE



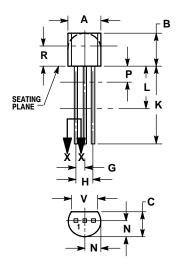


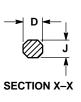
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PACKAGE DIMENSIONS

TO-92 (TO-226AA) CASE 29-11 ISSUE AL







NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED. 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

		INCHES		MILLIN	IETERS
	DIM	MIN	MAX	MIN	MAX
[Α	0.175	0.205	4.45	5.20
	В	0.170	0.210	4.32	5.33
	С	0.125	0.165	3.18	4.19
	D	0.016	0.021	0.407	0.533
	G	0.045	0.055	1.15	1.39
	Н	0.095	0.105	2.42	2.66
L	J	0.015	0.020	0.39	0.50
L	K	0.500		12.70	
	L	0.250		6.35	
	Ν	0.080	0.105	2.04	2.66
	Ρ		0.100		2.54
	R	0.115		2.93	
	۷	0.135		3.43	

<u>Notes</u>

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